



FCX589

#### 30V PNP MEDIUM POWER TRANSISTOR IN SOT89

#### **Features**

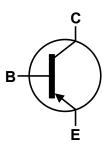
- BV<sub>CEO</sub> = -30V
- I<sub>C</sub> = -1A Continuous Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < -0.35V @ -1A</li>
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <a href="https://www.diodes.com/quality/product-definitions/">https://www.diodes.com/quality/product-definitions/</a>

### **Mechanical Data**

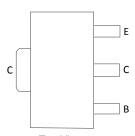
- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.05 grams (Approximate)







Device Symbol



Top View Pin Out

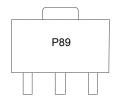
## **Ordering Information** (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
FCX589TA	Standard	P89	7	12	1,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**



P89 = Product Type Marking Code



### Absolute Maximum Ratings (@ TA = +25°C, unless otherwise specified.)

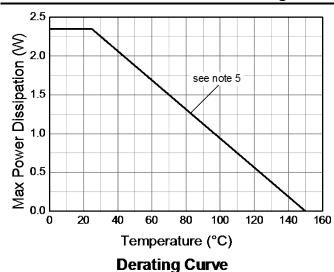
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-50	V
Collector-Emitter Voltage	$V_{CEO}$	-30	V
Emitter-Base Voltage	$V_{EBO}$	-5	V
Continuous Collector Current	Ι <sub>C</sub>	-1	Α
Peak Pulse Current	I <sub>CM</sub>	-2	Α
Base Current	lΒ	-200	mA

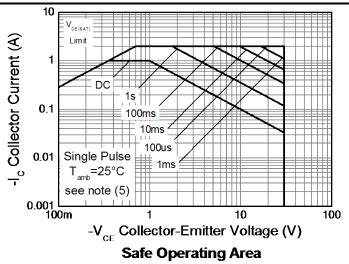
### Thermal Characteristics (@ TA = +25°C, unless otherwise specified.)

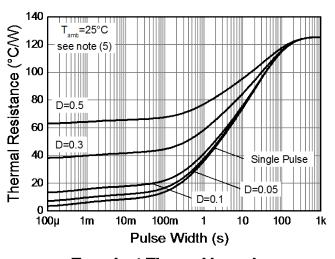
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	$P_{D}$	2.3	W
Operating and Storage Temperature Range	$T_{J_i} T_{STG}$	-55 to +150	°C

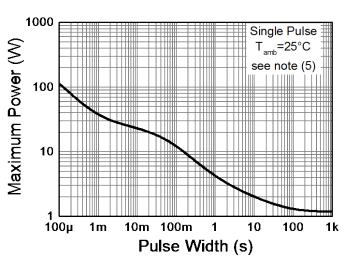
Notes: 5. For a device surface mounted on 25mm x 25mm x 0.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; device measured when operating in steady state condition.

## **Thermal Characteristics and Derating Information**









Transient Thermal Impedance

**Pulse Power Dissipation** 

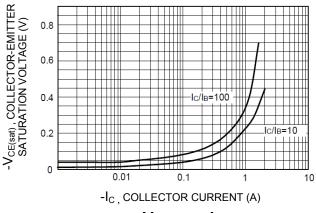


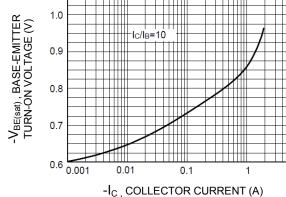
### Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	-50	_	_	V	I <sub>C</sub> = -100μA
Collector- Emitter Breakdown Voltage (Note 6)	$BV_{CEO}$	-30	_	_	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	$BV_{EBO}$	-5	_	_	V	I <sub>E</sub> = -100μA
Collector Cut-Off Current	I <sub>CBO</sub>	-	_	-100	nA	V <sub>CB</sub> = -30V
Emitter Cut-Off Current	I <sub>EBO</sub>	_	_	-100	nA	V <sub>EB</sub> = -4V
Collector Emitter Cut-Off Current	I <sub>CES</sub>	_	_	-100	nA	V <sub>CES</sub> = -30V
Collector-Emitter Saturation Voltage (Note 6)	V <sub>CE(sat)</sub>	_	_	-0.35 -0.65	V	$I_C = -1A$ , $I_B = -100mA$ $I_C = -2A$ , $I_B = -200mA$
Base-Emitter Saturation Voltage (Note 6)	V <sub>BE(sat)</sub>	-	_	-1.2	V	$I_C = -1A$ , $I_B = -100mA$
Base-Emitter Turn-On Voltage (Note 6)	$V_{BE(on)}$	I	_	-1.1	V	$I_C = -1A$ , $V_{CE} = -2V$
DC Current Gain (Note 6)	h <sub>FE</sub>	100 100 80 40	_	300 — —	_	$I_{C}$ = -1mA, $V_{CE}$ = -2V $I_{C}$ = -0.5A, $V_{CE}$ = -2V $I_{C}$ = -1A, $V_{CE}$ = -2V $I_{C}$ = -2A, $V_{CE}$ = -2V
Transitional frequency	$f_{T}$	100	_	_	MHz	$I_C = -100 \text{mA}, V_{CE} = -5V$ f = 100MHz
Output Capacitance	$C_{obo}$	_	_	15	pF	V <sub>CB</sub> = -10V, f = 1MHz

Note:

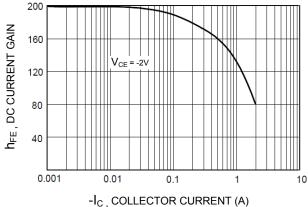
# Typical Electrical Characteristics (@ TA = +25°C, unless otherwise specified.)

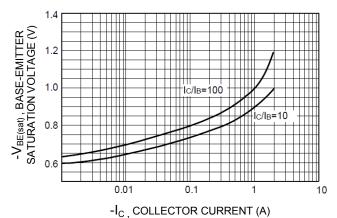




 $V_{CE(sat)} V I_C$ 







LCTOR CORREINT (A)

**V** 

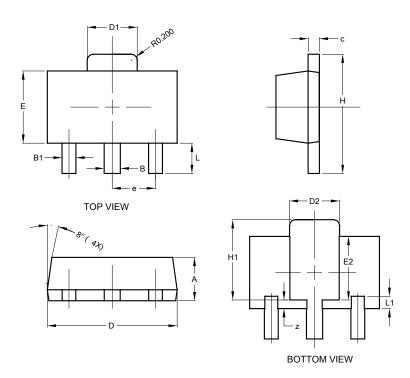
<sup>6.</sup> Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT89**

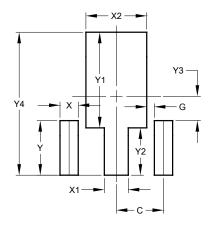


SOT89					
Dim	Min	Max	Тур		
A	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	ı	1.50		
Η	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT89



Dimensions	Value		
Dillielisions	(in mm)		
С	1.500		
G	0.244		
X	0.580		
X1	0.760		
X2	1.933		
Υ	1.730		
Y1	3.030		
Y2	1.500		
Y3	0.770		
Y4	4.530		



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